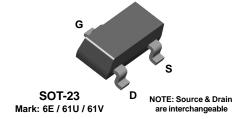


2N5460 2N5461 2N5462 MMBF5460 MMBF5461 MMBF5462





P-Channel General Purpose Amplifier

This device is designed primarily for low level audio and general purpose applications with high impedance signal sources. Sourced from Process 89.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{DG}	Drain-Gate Voltage	- 40	V	
V _{GS}	Gate-Source Voltage	40	V	
I _{GF}	Forward Gate Current	10	mA	
T _J ,T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES

1) These ratings are based on a maximum junction temperature of 150 degrees C.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max Ur		Units
		2N5460-5462	*MMBF5460-5462	
P_D	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/°C
R _{θJC}	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

P-Channel General Purpose Amplifier (continued)

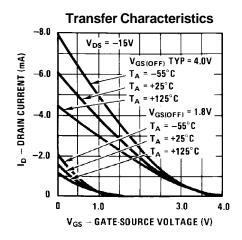
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
OFF CHA	RACTERISTICS					
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 10 \mu\text{A}, V_{DS} = 0$	40			V
Igss	Gate Reverse Current	V _{GS} = 20 V, V _{DS} = 0			5.0	nA
		$V_{GS} = 20 \text{ V}, V_{DS} = 0, T_A = 100^{\circ}\text{C}$			1.0	μΑ
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = 15 \text{ V}, I_D = 1.0 \mu\text{A}$ 5460			6.0	V
		546			7.5 9.0	V
Vgs	Cata Cauraa Valtaga	Vps = 15 V, lp = 0.1 mA 546			4.0	V
VGS	Gate-Source Voltage	V _{DS} = 15 V, I _D = 0.1 mA 546 0 V _{DS} = 15 V, I _D = 0.2 mA 546 0			4.0	V
		$V_{DS} = 15 \text{ V}, I_D = 0.2 \text{ mA}$ 546			6.0	v
ON CHAR IDSS	ACTERISTICS Zero-Gate Voltage Drain Current*	V _{DS} = 15 V, V _{GS} = 0 546 546 546	- 2.0		- 5.0 - 9.0 - 16	mA mA
	•		- 2.0		- 9.0	mA
IDSS	•	546	- 2.0		- 9.0	mA
IDSS SMALL SI	Zero-Gate Voltage Drain Current*	546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz	- 2.0 2 - 4.0		- 9.0 - 16	mA mA
IDSS	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS	546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546	- 2.0 2 - 4.0		- 9.0 - 16	mA mA
I _{DSS}	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS	546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546 546	1 - 2.0 2 - 4.0 0 1000 1 1500		- 9.0 - 16 4000 5000	mA mA
SMALL SI	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS	546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546	1 - 2.0 2 - 4.0 0 1000 1 1500		- 9.0 - 16	mA mA
SMALL SI	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS Forward Transfer Conductance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546 546 546 546	1 - 2.0 2 - 4.0 0 1000 1 1500	5.0	- 9.0 - 16 4000 5000 6000	mA mA μmhos μmhos μmhos
SMALL SI gfs Gos Ciss	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS Forward Transfer Conductance Output Conductance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546 546 546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz	1 - 2.0 2 - 4.0 0 1000 1 1500	5.0	- 9.0 - 16 4000 5000 6000 75	μmhos μmhos μmhos
SMALL SI gfs	Zero-Gate Voltage Drain Current* GNAL CHARACTERISTICS Forward Transfer Conductance Output Conductance Input Capacitance	V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz 546 546 546 V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz V _{DS} = 15 V, V _{GS} = 0, f = 1.0 kHz V _{DS} = 15 V, V _{GS} = 0, f = 1.0 MHz	1 - 2.0 2 - 4.0 0 1000 1 1500		- 9.0 - 16 4000 5000 6000 75 7.0	mA mA μmhos μmhos μmhos μmhos

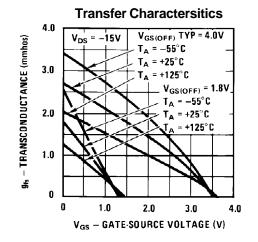
^{*}Pulse Test: Pulse Width \leq 300 ms, Duty Cycle \leq 2%

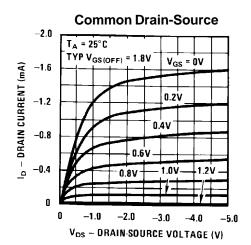
P-Channel General Purpose Amplifier

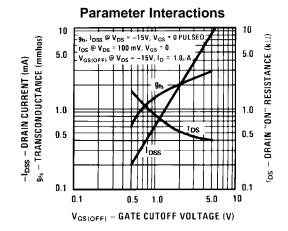
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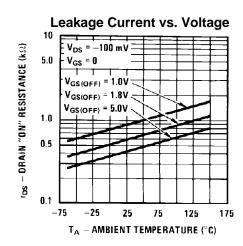
Typical Characteristics (continued)

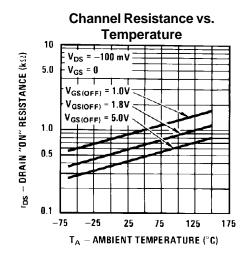








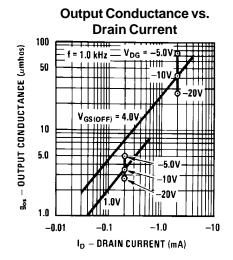


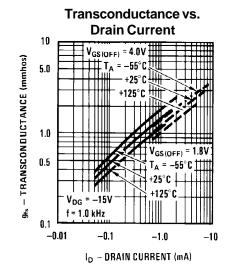


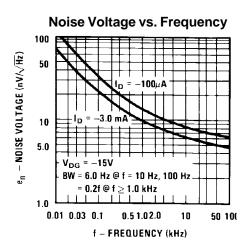
P-Channel General Purpose Amplifier

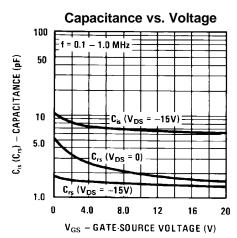
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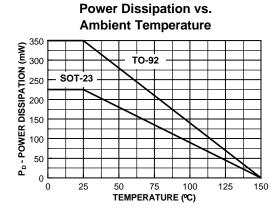
Typical Characteristics (continued)











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